

## FEATURES

### Low input currents

- 25 pA maximum input bias current
- 2 pA maximum input offset current

### High CMRR

- 92 dB CMRR (minimum) to 60 Hz,  $G = 10$
- 72 dB CMRR (minimum) at 5 kHz,  $G = 1$

### Excellent ac specifications and low power

- 1.5 MHz bandwidth ( $G = 1$ )
- 14 nV/ $\sqrt{\text{Hz}}$  input noise (1 kHz)
- Slew rate: 2 V/ $\mu\text{s}$

- 1 mA maximum quiescent supply current

### Versatile

- MSOP package
- Rail-to-rail output
- Input voltage range to below negative supply rail
- 7 kV ESD HBM protection
- 4.5 V to 36 V single supply
- $\pm 2.25$  V to  $\pm 18$  V dual supply
- Gain set with single resistor ( $G = 1$  to 1000)

## ENHANCED PRODUCT FEATURES

Supports defense and aerospace applications (AQEC standard)

Extended industrial temperature range:  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$

Controlled manufacturing baseline

1 assembly/test site

1 fabrication site

Product change notification

Qualification data available on request

## APPLICATIONS

Medical instrumentation

Precision data acquisition

Transducer interfaces

## GENERAL DESCRIPTION

The **AD8220-EP** is the first single-supply, JFET input instrumentation amplifier available in an MSOP package. Designed to meet the needs of high performance, portable instrumentation, the **AD8220-EP** has a minimum common-mode rejection ratio (CMRR) of 77 dB at dc and a minimum CMRR of 72 dB at 5 kHz for  $G = 1$ . Maximum input bias current at  $25^{\circ}\text{C}$  is 25 pA and remains below 100 nA over the entire extended industrial temperature range. Despite the JFET inputs, the **AD8220-EP** typically has a noise corner of only 10 Hz.

With the proliferation of mixed-signal processing, the number of power supplies required in each system has grown. The **AD8220-EP** is designed to alleviate this problem. The **AD8220-EP**

## PIN CONFIGURATION

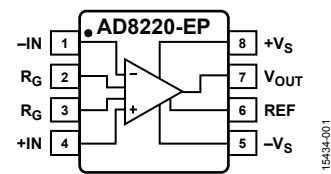


Figure 1.

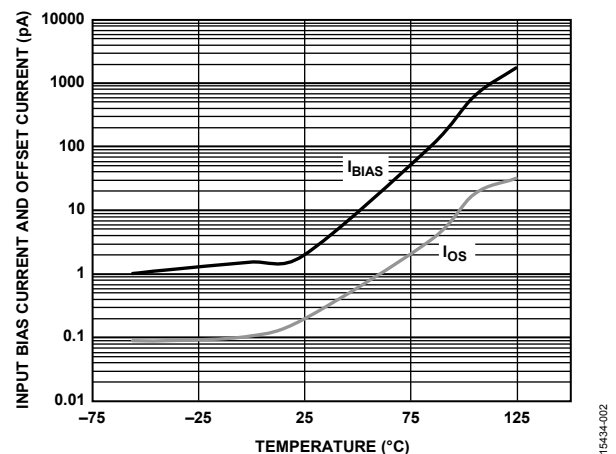


Figure 2. Input Bias Current and Offset Current vs. Temperature

can operate on a  $\pm 18$  V dual supply, as well as on a single 5 V supply. Its rail-to-rail output stage maximizes dynamic range on the low voltage supplies common in portable applications. Its ability to run on a single 5 V supply eliminates the need to use higher voltage, dual supplies. The **AD8220-EP** draws a maximum of 750  $\mu\text{A}$  of quiescent current at  $25^{\circ}\text{C}$ , making it ideal for battery powered devices.

Gain is set from 1 to 1000 with a single resistor. Increasing the gain increases the common-mode rejection. Measurements that need higher CMRR when reading small signals benefit when the **AD8220-EP** is set for large gains.

A reference pin allows the user to offset the output voltage. This feature is useful when interfacing with analog-to-digital converters.

The **AD8220-EP** is available in an MSOP that takes roughly half the board area of an SOIC. Performance is specified over the extended industrial temperature range of  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

Additional application and technical information can be found in the **AD8220** data sheet.

Rev. A

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**TABLE OF CONTENTS**

Features .....	1	Absolute Maximum Ratings .....	7
Enhanced Product Features .....	1	ESD Caution.....	7
Applications.....	1	Pin Configuration and Function Descriptions.....	8
General Description .....	1	Typical Performance Characteristics .....	9
Pin Configuration.....	1	Outline Dimensions .....	11
Revision History .....	2	Ordering Guide .....	11
Specifications.....	3		

**REVISION HISTORY**

**11/2017—Rev. 0 to Rev. A**

Changes to Table 1 .....	4
Changes to Input Offset, $V_{OS1}$ , Average TC Parameter, Table 2.....	5

**4/2017—Revision 0: Initial Version**

## SPECIFICATIONS

+V<sub>S</sub> = 15 V, -V<sub>S</sub> = -15 V, V<sub>REF</sub> = 0 V, T<sub>A</sub> = 25°C, T<sub>OPR</sub> = -55°C to +125°C, G = 1, R<sub>L</sub> = 2 kΩ,<sup>1</sup> unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
<b>COMMON-MODE REJECTION RATIO (CMRR)</b>					
CMRR from DC to 60 Hz with 1 kΩ Source Imbalance	T <sub>OPR</sub> V <sub>CM</sub> = ±10 V				
G = 1		77			dB
G = 10		92			dB
G = 100		92			dB
G = 1000		92			dB
CMRR at 5 kHz	V <sub>CM</sub> = ±10 V				
G = 1		72			dB
G = 10		80			dB
G = 100		80			dB
G = 1000		80			dB
<b>NOISE</b>					
Voltage Noise, 1 kHz	Referred to input (RTI) noise = $\sqrt{(e_{ni}^2 + (e_{no}/G)^2)}$ , T <sub>A</sub>				
Input Voltage Noise, e <sub>ni</sub>	V <sub>IN+</sub> , V <sub>IN-</sub> = 0 V		14		nV/√Hz
Output Voltage Noise, e <sub>no</sub>	V <sub>IN+</sub> , V <sub>IN-</sub> = 0 V		90		nV/√Hz
RTI, 0.1 Hz to 10 Hz					
G = 1			5		μV p-p
G = 1000			0.8		μV p-p
Current Noise	f = 1 kHz		1		fA/√Hz
<b>VOLTAGE OFFSET</b>					
Input Offset, V <sub>OSI</sub>	V <sub>OS</sub> = V <sub>OSI</sub> + V <sub>OSO</sub> /G				
Average Temperature Coefficient (TC)	T <sub>A</sub>	-250		+250	μV
Output Offset, V <sub>OSO</sub>	T <sub>OPR</sub>	-10		+10	μV/°C
Average TC	T <sub>A</sub>	-750		+750	μV
Offset RTI vs. Supply (PSR)	T <sub>OPR</sub>	-10		+10	μV/°C
G = 1	V <sub>S</sub> = ±5 V to ±15 V, T <sub>OPR</sub>		80		dB
G = 10			92		dB
G = 100			92		dB
G = 1000			92		dB
<b>INPUT CURRENT</b>					
Input Bias Current	T <sub>A</sub>			25	pA
Over Temperature	T <sub>OPR</sub>			100	nA
Input Offset Current	T <sub>A</sub>			2	pA
Over Temperature	T <sub>OPR</sub>			10	nA
<b>DYNAMIC RESPONSE</b>					
Small Signal Bandwidth, -3 dB	T <sub>A</sub>				
G = 1			1500		kHz
G = 10			800		kHz
G = 100			120		kHz
G = 1000			14		kHz
Settling Time 0.01%	10 V step, T <sub>A</sub>				
G = 1			5		μs
G = 10			4.3		μs
G = 100			8.1		μs
G = 1000			58		μs

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
Settling Time 0.001%	10 V step, $T_A$				
$G = 1$			6		$\mu\text{s}$
$G = 10$			4.6		$\mu\text{s}$
$G = 100$			9.6		$\mu\text{s}$
$G = 1000$			74		$\mu\text{s}$
Slew Rate					
$G = 1$ to 100	$T_A$	2			$\text{V}/\mu\text{s}$
<b>GAIN</b>	$G = 1 + (49.4 \text{ k}\Omega/R_G)$ , $T_{\text{OPR}}$				
Gain Range		1		1000	$\text{V}/\text{V}$
Gain Error	$V_{\text{OUT}} = \pm 10 \text{ V}$				
$G = 1$		-0.1		+0.1	%
$G = 10$		-0.8		+0.8	%
$G = 100$		-0.8		+0.8	%
$G = 1000$		-0.8		+0.8	%
Gain Nonlinearity	$V_{\text{OUT}} = -10 \text{ V to } +10 \text{ V}$ , $T_A$				
$G = 1$	$R_L = 10 \text{ k}\Omega$		10	15	ppm
$G = 10$	$R_L = 10 \text{ k}\Omega$		5	10	ppm
$G = 100$	$R_L = 10 \text{ k}\Omega$		30	60	ppm
$G = 1000$	$R_L = 10 \text{ k}\Omega$		400	500	ppm
$G = 1$	$R_L = 2 \text{ k}\Omega$		10	15	ppm
$G = 10$	$R_L = 2 \text{ k}\Omega$		10	15	ppm
$G = 100$	$R_L = 2 \text{ k}\Omega$		50	75	ppm
Gain vs. Temperature					
$G = 1$			3	10	ppm/ $^{\circ}\text{C}$
$G > 10$				-50	ppm/ $^{\circ}\text{C}$
<b>INPUT</b>					
Impedance (Pin to Ground) <sup>2</sup>	$T_A$		$10^4    5$		$\text{G}\Omega    \text{pF}$
Input Operating Voltage Range <sup>3</sup>	$V_S = \pm 2.25 \text{ V to } \pm 18 \text{ V}$ for dual supplies, $T_A$	$-V_S - 0.1$		$+V_S - 2$	$\text{V}$
Over Temperature	$T_{\text{OPR}}$	$-V_S - 0.1$		$+V_S - 2.2$	$\text{V}$
<b>OUTPUT</b>					
Output Swing	$R_L = 10 \text{ k}\Omega$ , $T_A$	-14.7		+14.7	$\text{V}$
Over Temperature	$T_{\text{OPR}}$	-14.3		+14.3	$\text{V}$
Short-Circuit Current	$T_A$		15		$\text{mA}$
<b>REFERENCE INPUT</b>	$T_A$				
$R_{\text{IN}}$			40		$\text{k}\Omega$
$I_{\text{IN}}$	$V_{\text{IN}+}, V_{\text{IN}-} = 0 \text{ V}$			70	$\mu\text{A}$
Voltage Range				$+V_S$	$\text{V}$
Gain to Output	$T_A$			$1 \pm 0.0001$	$\text{V}/\text{V}$
<b>POWER SUPPLY</b>					
Operating Range <sup>4</sup>		$\pm 2.25$		$\pm 18$	$\text{V}$
Quiescent Current	$T_A$			750	$\mu\text{A}$
Over Temperature	$T_{\text{OPR}}$			1000	$\mu\text{A}$
<b>TEMPERATURE RANGE</b>					
For Specified Performance	$T_{\text{OPR}}$	-55		+125	$^{\circ}\text{C}$

<sup>1</sup> When the output sinks more than 4 mA, use a 47 pF capacitor in parallel with the load to prevent ringing. Otherwise, use a larger load, such as 10 k $\Omega$ .

<sup>2</sup> Differential and common-mode input impedance ( $Z_{\text{DIFF}}$  and  $Z_{\text{CM}}$ ) can be calculated from the pin impedance ( $Z_{\text{PIN}}$ ):  $Z_{\text{DIFF}} = 2(Z_{\text{PIN}})$ ;  $Z_{\text{CM}} = Z_{\text{PIN}}/2$ .

<sup>3</sup> The AD8220-EP can operate up to a diode drop below the negative supply but the bias current increases sharply. The input voltage range reflects the maximum allowable voltage where the input bias current is within the specification.

<sup>4</sup> At the minimum supply voltage of  $\pm 2.25 \text{ V}$ , ensure that the input common-mode voltage is within the input voltage range specification.

+V<sub>S</sub> = 5 V, -V<sub>S</sub> = 0 V, V<sub>REF</sub> = 2.5 V, T<sub>A</sub> = 25°C, T<sub>OPR</sub> = -55°C to +125°C, G = 1, R<sub>L</sub> = 2 kΩ<sup>1</sup>, unless otherwise noted.

Table 2.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
COMMON-MODE REJECTION RATIO (CMRR)	T <sub>OPR</sub>				
CMRR from DC to 60 Hz with 1 kΩ Source Imbalance	V <sub>CM</sub> = 0 V to 2.5 V				
G = 1		77			dB
G = 10		92			dB
G = 100		92			dB
G = 1000		92			dB
CMRR at 5 kHz	V <sub>CM</sub> = 0 V to 2.5 V				
G = 1		72			dB
G = 10		80			dB
G = 100		80			dB
G = 1000		80			dB
NOISE	RTI noise = $\sqrt{(e_{ni}^2 + (e_{no}/G)^2)}$ , T <sub>A</sub>				
Voltage Noise, 1 kHz	V <sub>S</sub> = ±2.5 V				
Input Voltage Noise, e <sub>ni</sub>	V <sub>IN+</sub> , V <sub>IN-</sub> = 0 V, V <sub>REF</sub> = 0 V		14		nV/√Hz
Output Voltage Noise, e <sub>no</sub>	V <sub>IN+</sub> , V <sub>IN-</sub> = 0 V, V <sub>REF</sub> = 0 V		90		nV/√Hz
RTI, 0.1 Hz to 10 Hz					
G = 1			5		μV p-p
G = 1000			0.8		μV p-p
Current Noise	f = 1 kHz		1		fA/√Hz
VOLTAGE OFFSET	V <sub>OS</sub> = V <sub>OSI</sub> + V <sub>OSO</sub> /G				
Input Offset, V <sub>OSI</sub>	T <sub>A</sub>	-300		+300	μV
Average TC	T <sub>OPR</sub>	-10		+10	μV/°C
Output Offset, V <sub>OSO</sub>	T <sub>A</sub>	-800		+800	μV
Average TC	T <sub>OPR</sub>	-10		+10	μV/°C
Offset RTI vs. Supply (PSR)	T <sub>OPR</sub>				
G = 1		80			dB
G = 10		92			dB
G = 100		92			dB
G = 1000		92			dB
INPUT CURRENT					
Input Bias Current	T <sub>A</sub>			25	pA
Over Temperature	T <sub>OPR</sub>			100	nA
Input Offset Current	T <sub>A</sub>			2	pA
Over Temperature	T <sub>OPR</sub>			10	nA
DYNAMIC RESPONSE	T <sub>A</sub>				
Small Signal Bandwidth, -3 dB					
G = 1			1500		kHz
G = 10			800		kHz
G = 100			120		kHz
G = 1000			14		kHz
Settling Time 0.01%	T <sub>A</sub>				
G = 1	3 V step		2.5		μs
G = 10	4 V step		2.5		μs
G = 100	4 V step		7.5		μs
G = 1000	4 V step		30		μs
Settling Time 0.001%	T <sub>A</sub>				
G = 1	3 V step		3.5		μs
G = 10	4 V step		3.5		μs
G = 100	4 V step		8.5		μs
G = 1000	4 V step		37		μs

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
Slew Rate G = 1 to 100	T <sub>A</sub>	2			V/μs
GAIN	G = 1 + (49.4 kΩ/R <sub>G</sub> ), T <sub>OPR</sub>	1		1000	V/V
Gain Range					
Gain Error	V <sub>OUT</sub> = 0.3 V to 2.9 V for G = 1, V <sub>OUT</sub> = 0.3 V to 3.8 V for G > 1				
G = 1		-0.1		+0.1	%
G = 10		-0.8		+0.8	%
G = 100		-0.8		+0.8	%
G = 1000		-0.8		+0.8	%
Nonlinearity	V <sub>OUT</sub> = 0.3 V to 2.9 V for G = 1, V <sub>OUT</sub> = 0.3 V to 3.8 V for G > 1, T <sub>A</sub>				
G = 1	R <sub>L</sub> = 10 kΩ			50	ppm
G = 10	R <sub>L</sub> = 10 kΩ			50	ppm
G = 100	R <sub>L</sub> = 10 kΩ			75	ppm
G = 1000	R <sub>L</sub> = 10 kΩ			750	ppm
G = 1	R <sub>L</sub> = 2 kΩ			50	ppm
G = 10	R <sub>L</sub> = 2 kΩ			50	ppm
G = 100	R <sub>L</sub> = 2 kΩ			75	ppm
Gain vs. Temperature					
G = 1			3	10	ppm/°C
G > 10				-50	ppm/°C
INPUT					
Impedance (Pin to Ground) <sup>2</sup>	T <sub>A</sub>		10 <sup>4</sup>   6		GΩ  pF
Input Voltage Range <sup>3</sup>	T <sub>A</sub>				V
Over Temperature	T <sub>OPR</sub>	-0.1		+V <sub>S</sub> - 2.2	V
OUTPUT					
Output Swing	R <sub>L</sub> = 10 kΩ	0.15		4.85	V
Over Temperature	T <sub>OPR</sub>	0.3		4.70	V
Short-Circuit Current			15		mA
REFERENCE INPUT					
R <sub>IN</sub>	T <sub>A</sub>		40		kΩ
I <sub>IN</sub>	V <sub>IN+</sub> , V <sub>IN-</sub> = 0 V			70	μA
Voltage Range		-V <sub>S</sub>		+V <sub>S</sub>	V
Gain to Output	T <sub>A</sub>		1 ± 0.0001		V/V
POWER SUPPLY					
Operating Range		4.5		36	V
Quiescent Current	T <sub>A</sub>			750	μA
Over Temperature	T <sub>OPR</sub>			1000	μA
TEMPERATURE RANGE					
T <sub>OPR</sub> , For Specified Performance	T <sub>OPR</sub>	-55		+125	°C

<sup>1</sup> When the output sinks more than 4 mA, use a 47 pF capacitor in parallel with the load to prevent ringing. Otherwise, use a larger load, such as 10 kΩ.

<sup>2</sup> Differential and common-mode impedance can be calculated from the pin impedance: Z<sub>DIFF</sub> = 2(Z<sub>PIN</sub>); Z<sub>CM</sub> = Z<sub>PIN</sub>/2.

<sup>3</sup> The AD8220-EP can operate up to a diode drop below the negative supply but the bias current increases sharply. The input voltage range reflects the maximum allowable voltage where the input bias current is within the specification.

## ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage	$\pm 18$ V
Power Dissipation	See Figure 3
Output Short-Circuit Current	Indefinite <sup>1</sup>
Input Voltage (Common Mode)	$\pm V_S$
Differential Input Voltage	$\pm V_S$
Storage Temperature Range	$-65^\circ\text{C}$ to $+125^\circ\text{C}$
Operating Temperature Range	$-55^\circ\text{C}$ to $+125^\circ\text{C}$
Reflow Temperature	$260^\circ\text{C}$
Junction Temperature	$140^\circ\text{C}$
$\theta_{JA}$ (4-Layer JEDEC Standard Board) <sup>2</sup>	$189^\circ\text{C/W}$
ESD	
Human Body Model	7 kV
Charge Device Model	1.25 kV
Machine Model	0.4 kV

<sup>1</sup> Assumes the load is referenced to midsupply.

<sup>2</sup>  $\theta_{JA}$  value is an approximation.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Figure 3 shows the maximum safe power dissipation in the package vs. the ambient temperature for the MSOP on a 4-layer JEDEC standard board.

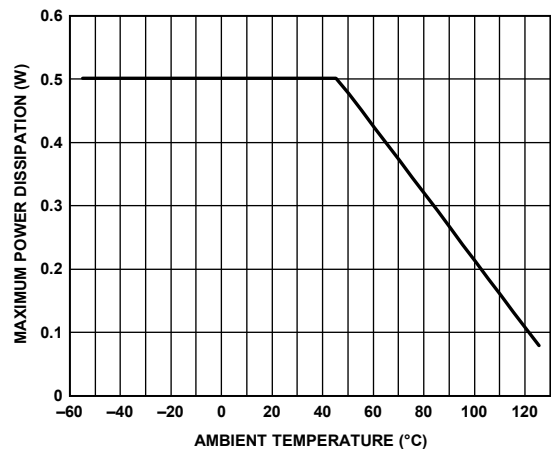


Figure 3. Maximum Power Dissipation vs. Ambient Temperature

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

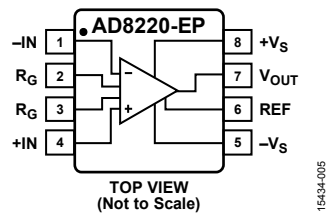


Figure 4. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	-IN	Negative Input Terminal (True Differential Input).
2, 3	R <sub>G</sub>	Gain Setting Terminals. Place a resistor across the R <sub>G</sub> pins.
4	+IN	Positive Input Terminal (True Differential Input).
5	-V <sub>S</sub>	Negative Power Supply Terminal.
6	REF	Reference Voltage Terminal. Drive this terminal with a low impedance voltage source to level shift the output.
7	V <sub>OUT</sub>	Output Terminal.
8	+V <sub>S</sub>	Positive Power Supply Terminal.



TYPICAL PERFORMANCE CHARACTERISTICS

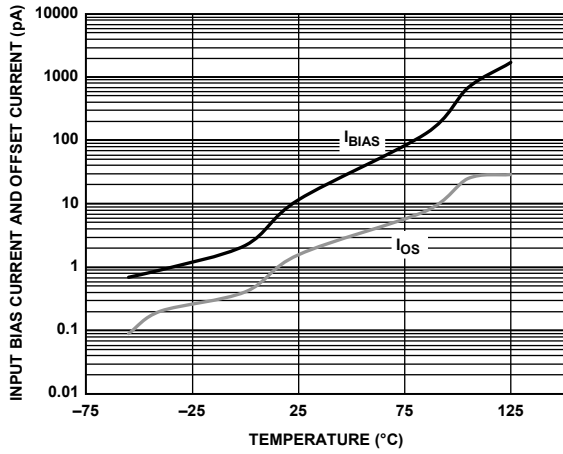


Figure 5. Input Bias Current and Offset Current vs. Temperature,  $V_S = \pm 15\text{ V}$ ,  $V_{REF} = 0\text{ V}$

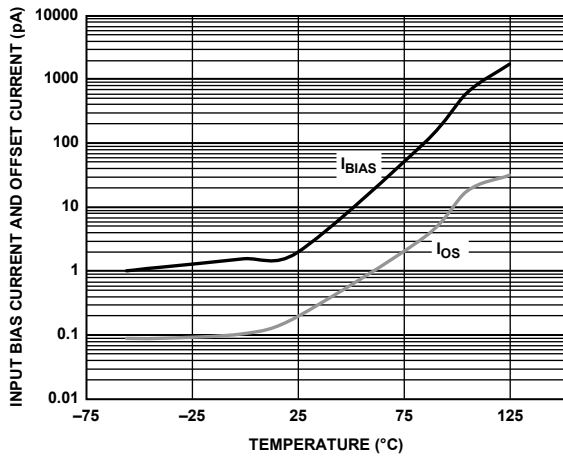


Figure 6. Input Bias Current and Offset Current vs. Temperature,  $V_S = 5\text{ V}$ ,  $V_{REF} = 2.5\text{ V}$

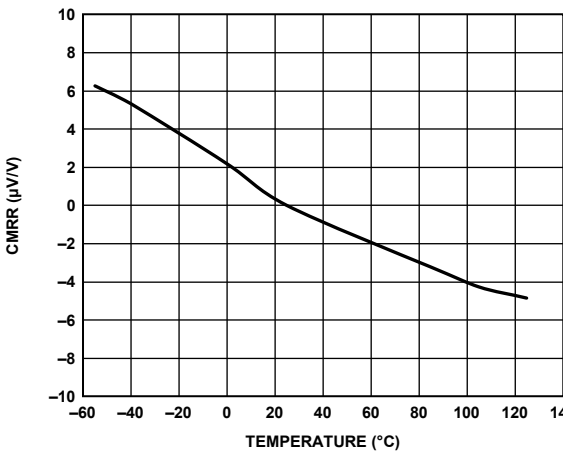


Figure 7. CMRR vs. Temperature,  $G = 1$

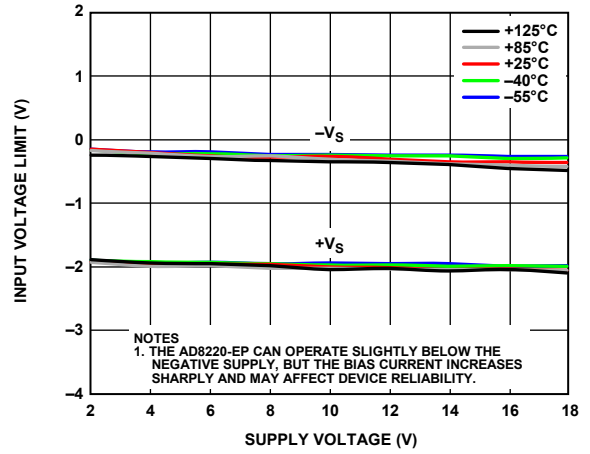


Figure 8. Input Voltage Limit vs. Supply Voltage,  $G = 1$ ,  $V_{REF} = 0\text{ V}$

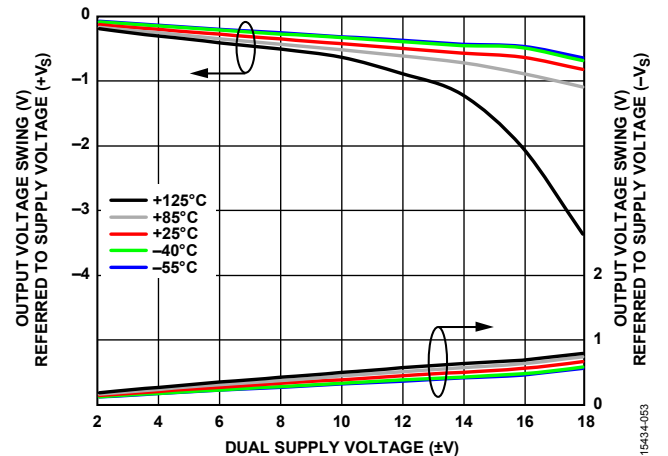


Figure 9. Output Voltage Swing Referred to Supply Voltage vs. Dual Supply Voltage,  $R_{LOAD} = 2\text{ k}\Omega$ ,  $G = 10$ ,  $V_{REF} = 0\text{ V}$

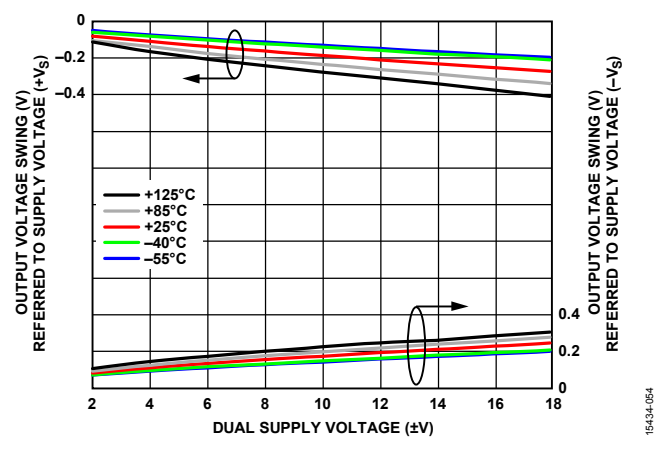


Figure 10. Output Voltage Swing Referred to Supply Voltage vs. Dual Supply Voltage,  $R_{LOAD} = 10\text{ k}\Omega$ ,  $G = 10$ ,  $V_{REF} = 0\text{ V}$

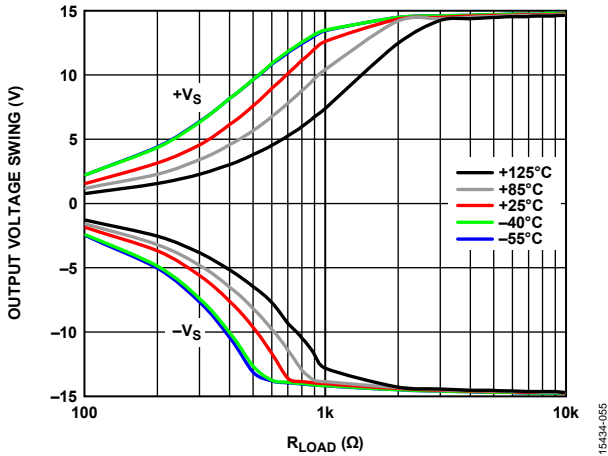


Figure 11. Output Voltage Swing vs. Load Resistance ( $R_{LOAD}$ ),  $V_S = \pm 15 V$ ,  $V_{REF} = 0 V$

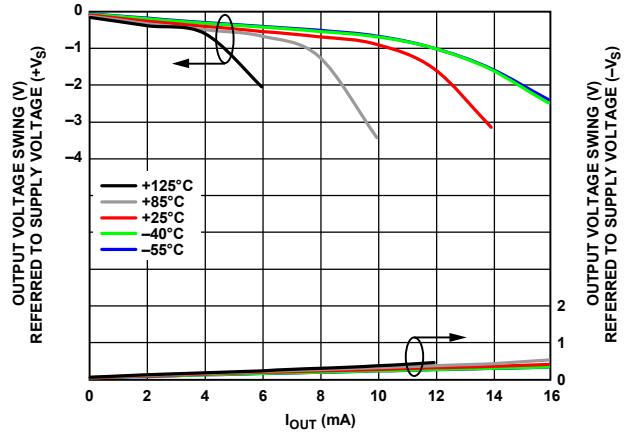


Figure 13. Output Voltage Swing Referred to Supply Voltage vs. Output Current ( $I_{OUT}$ ),  $V_S = \pm 15 V$ ,  $V_{REF} = 0 V$

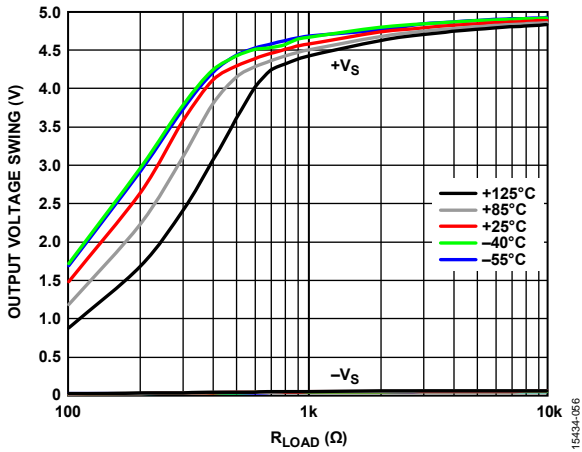


Figure 12. Output Voltage Swing vs. Load Resistance ( $R_{LOAD}$ ),  $V_S = 5 V$ ,  $V_{REF} = 2.5 V$

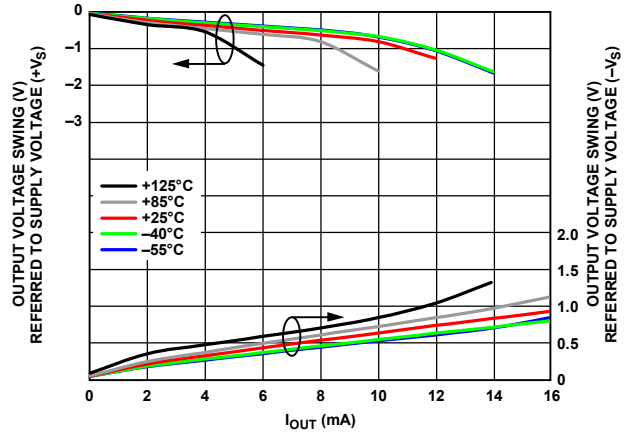
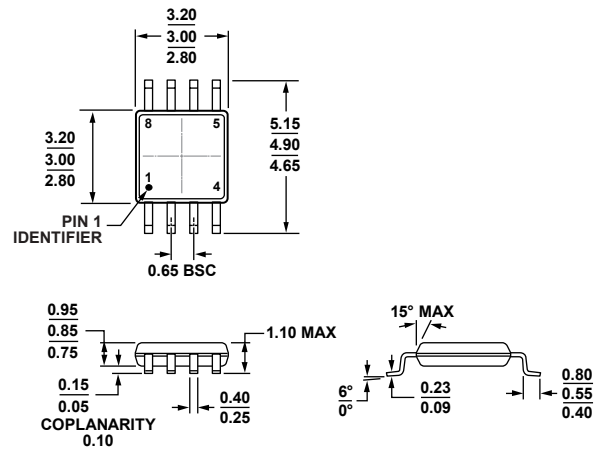


Figure 14. Output Voltage Swing Referred to Supply Voltage vs. Output Current ( $I_{OUT}$ ),  $V_S = 5 V$ ,  $V_{REF} = 2.5 V$

# OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 15. 8-Lead Mini Small Outline Package [MSOP] (RM-8)

Dimensions shown in millimeters

10-07-2008-B

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Branding
AD8220TRMZ-EP	-55°C to +125°C	8-Lead MSOP	RM-8	Y6T
AD8220TRMZ-EP-R7	-55°C to +125°C	8-Lead MSOP, 7" Tape and Reel	RM-8	Y6T

<sup>1</sup> Z = RoHS Compliant Part.